## NSN 5961-01-310-9403

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Inclosure Material:
Ceramic
Internal Configuration:
Field effect
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
20.0 gate to source voltage and 80.0 drain to source voltage and 80.0 drain to gate voltage
Current Rating Per Characteristic:
0.50 amperes drain current
Power Rating Per Characteristic:
10.0 watts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0